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## Effect of Y<sup>3+</sup> on the local structure and luminescent properties of

## La<sub>3-x</sub>Y<sub>x</sub>Si<sub>6</sub>N<sub>11</sub>:Ce<sup>3+</sup> phosphors for high power LED lighting

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**Table S1.** Atomic coordinates and isotropic displacement parameters of  $La_{2.86-x}Y_xSi_6N_{11}$ :0.14Ce<sup>3+</sup> (x = 0.1, 0.5, 0.9) from the Rietveld Refinement of SPD.

$La_{2.86-x}Y_xSi_6N_{11}:0.14Ce^{3+}(x=0.1)$					
	x	У	Z	Осси.	Biso.
La <sub>(1)</sub>	0.3187	0.1813	0.6392	0.958	0.675
Y <sub>(1)</sub>	0.3187	0.1813	0.6392	0.042	0.675
La <sub>(2)</sub>	0	0	0.6554	0.984	0.675
Y <sub>(2)</sub>	0	0	0.6554	0.016	0.675
$Si_{(1)}$	0.0781	0.2102	0.1229	1.000	0.418
Si <sub>(2)</sub>	0.6176	0.1176	0.6103	1.000	0.418
N <sub>(1)</sub>	0.0740	0.2288	0.4723	1.000	0.427
N <sub>(2)</sub>	0.6542	0.1543	0.9622	1.000	0.427
N <sub>(3)</sub>	0	0.1777	0.0204	1.000	0.427
N <sub>(4)</sub>	0.5000	0	0.5771	1.000	0.427

	]	$La_{2.86-x}Y_xSi_6N_{11}:0.14Ce^{3+}(x=0.5)$				
	x	У	Z	Осси.	Biso.	
La <sub>(1)</sub>	0.3187	0.1813	0.6418	0.886	0.662	
Y <sub>(1)</sub>	0.3187	0.1813	0.6418	0.114	0.662	
La(2)	0	0	0.6651	0.728	0.662	
Y <sub>(2)</sub>	0	0	0.66651	0.272	0.662	
$Si_{(1)}$	0.0765	0.2102	0.1250	1.000	0.400	
Si <sub>(2)</sub>	0.6183	0.1183	0.6090	1.000	0.400	
N <sub>(1)</sub>	0.0740	0.2288	0.4723	1.000	0.400	
N <sub>(2)</sub>	0.6518	0.1518	0.9600	1.000	0.400	
N <sub>(3)</sub>	0	0.1764	0.0155	1.000	0.400	
N <sub>(4)</sub>	0.5000	0	0.5673	1.000	0.400	

$La_{2.86-x}Y_xSi_6N_{11}:0.14Ce^{3+}(x=0.9)$					
	x	у	z	Осси.	Biso.
La <sub>(1)</sub>	0.3205	0.1795	0.6701	0.743	0.816
Y <sub>(1)</sub>	0.3161	0.1838	0.6819	0.257	0.816
La(2)	0	0	0.6911	0.613	0.816
Y <sub>(2)</sub>	0	0	0.6911	0.387	0.816
Si <sub>(1)</sub>	0.0770	0.2094	0.1513	1.000	0.400
Si <sub>(2)</sub>	0.6179	0.1179	0.6387	1.000	0.400
N <sub>(1)</sub>	0.0770	0.2319	0.5085	1.000	0.400
N <sub>(2)</sub>	0.6554	0.1554	0.9926	1.000	0.400
N <sub>(3)</sub>	0	0.1759	0.0466	1.000	0.400
N <sub>(4)</sub>	0.5000	0	0.6077	1.000	0.400

 Table S2.
 Crystallographic
 Data
 after
 Refinements
 of
  $La_{2.86-}$ 
 $_xY_xSi_6N_{11}:0.14Ce^{3+}$  (x = 0, 0.1, 0.3, 0.5, 0.7, 0.9)

X	a (Å)	<b>c</b> (Å)	$V_{\rm La(1)/Y(1)}({\rm \AA}^3)$	$V_{\rm La(2)/Y(2)}({\rm \AA}^3)$	Bond La <sub>(2)</sub> -N (Å)
0	10.1885	4.840	28.2793	29.8939	2.6362
0.1	10.1793	4.841	28.1770	29.6197	2.6280
0.3	10.1573	4.840	27.8490	29.2873	2.6146
0.5	10.137	4.847	27.5418	28.9138	2.5987
0.7	10.1231	4.841	27.2333	28.1523	2.5926
0.9	10.1143	4.842	27.1696	27.6786	2.5892



Figure S1. PL spectra of  $La_{3-z}Si_6N_{11}$ :zCe<sup>3+</sup> with varying Ce<sup>3+</sup> concentrations (z = 0.08, 0.10, 0.12, 0.14, 0.16, 0.18, 0.20)



Figure S2. The cell parameters a and c of  $La_{2.86-x}Y_xSi_6N_{11}$ :0.14Ce<sup>3+</sup>.



Figure S3. Excitation spectra of  $La_{2.86-x}Y_xSi_6N_{11}:0.14Ce^{3+}$  (x = 0, 0.05,

0.1, 0.3, 0.5, 0.7, 0.9).



**Figure S4.** The configurational coordinate of the ground state of  $Ce^{3+}$  and the excited states of  $Ce^{3+}$  in LSN and LYSN phosphors.